## **EAST Search History**

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	137606	(thin adj film adj transistor\$2 tft electro\$1optic\$4 transistor\$2).ti, clm,ab.	USPAT	OR	ON	2007/05/29 17:15
L2	40168	((amorphous adj1 silicon ".alpha.si" "a-si" polysilicon polycrystalline \$6crystalline silicon)near32 (lattice plane orient\$6))	USPAT	OR	ON	2007/05/29 17:19
L3	1433	(lattice plane orient\$6) near7 (determin\$4 detect\$4 sens\$4)near4 (diffract\$5 backscatter\$4)	USPAT	OR	ON	2007/05/29 17:12
L4	28	1 and 2 and 3	USPAT	OR	ON	2007/05/29 17:19
L5	56579	(thin adj film adj transistor\$2 tft electro\$1optic\$4 transistor\$2).ti, clm,ab.	US-PGPUB	OR	ON	2007/05/29 18:13
L6	19080	((amorphous adj1 silicon ".alpha.si" "a-si" polysilicon polycrystalline \$6crystalline silicon)near32 (lattice plane orient\$6))	US-PGPUB	OR	ON	2007/05/29 18:12
L7	584	(lattice plane orient\$6) near7 (determin\$4 detect\$4 sens\$4)near4 (diffract\$5 backscatter\$4)	US-PGPUB	OR	ON	2007/05/29 17:16
L8	27	5 and 6 and 7	US-PGPUB	OR	ON	2007/05/29 17:12
L9	455786	(thin adj film adj transistor\$2 tft electro\$1optic\$4 transistor\$2)	EPO; JPO; DERWENT	OR	ON	2007/05/29 17:15
L10	18775	((amorphous adj1 silicon ".alpha.si" "a-si" polysilicon polycrystalline \$6crystalline silicon)near32 (lattice plane orient\$6))	EPO; JPO; DERWENT	OR	ON	2007/05/29 17:15
L11	1164	(lattice plane orient\$6) and (determin\$4 detect\$4 sens\$4)near4 (diffract\$5 backscatter\$4)	EPO; JPO; DERWENT	OR	ON	2007/05/29 17:16
L12	12	9 and 10 and 11	EPO; JPO; DERWENT	OR	ON	2007/05/29 17:17
L13	144	(("101" "{101}" "{101}" "[101]" "101")and ("001" "{001}" "{001}" "[001]" "001") and ("111" "{111}" "{111}" "[111]" "111")).ab,clm.	US-PGPUB; USPAT	OR	ON	2007/05/29 18:06
L14	24	((amorphous adj1 silicon ".alpha.si" "a-si" polysilicon polycrystalline \$6crystalline silicon)near32 (lattice plane orient\$6)) and 13	US-PGPUB; USPAT	OR	ON	2007/05/29 18:15
L15	1808	(257/359 257/64 257/65 257/66 25 7/627 257/628.ccls.)	USPAT	OR	ON	2007/05/29 18:04
L16	1270	(@ad<="20010606") and 15	USPAT	OR	ON	2007/05/29 17:51

## **EAST Search History**

L17	521	(257/627 257/628.ccls.)	USPAT	OR	ON	2007/05/29 17:51
L18	369	(@ad<="20010606") and 17	USPAT	OR	ON	2007/05/29 17:51
L19	7471	(257/E21.413 257/E27. 111 257/E29.004 257/E29. 137 257/E29.151 257/E29.279.ccls.	US-PGPUB; USPAT	OR	ON	2007/05/29 18:15
L20	50	(("101" "{101}" "{101}" "[101]" "101")and ("001" "{001}" "{001}" "[001]" "001") and ("111" "{111}" "{111}" "[111]" "111"))and 19	US-PGPUB; USPAT	OR	ON	2007/05/29 18:11
L22	6276	(("101" "{101}" "{101}" "[101]" "101")same ("001" "{001}" "{001}" "[001]" "001") same("111" "{111}" "{111}" "[111]" "111"))	US-PGPUB; USPAT	OR	ON	2007/05/29 18:11
L23	149	((amorphous adj1 silicon ".alpha.si" "a-si" polysilicon polycrystalline \$6crystalline silicon)near32 (lattice plane orient\$6)) and 22	US-PGPUB; USPAT	OR	ON	2007/05/29 18:12
L24	194185	(thin adj film adj transistor\$2 tft electro\$1optic\$4 transistor\$2).ti, clm,ab.	US-PGPUB; USPAT	OR	ON	2007/05/29 18:13
L25	28	23 and 24	US-PGPUB; USPAT	OR	ON	2007/05/29 18:13
L26	1017	(257/E21.413 257/E27. 111 257/E29.004 257/E29. 137 257/E29.151 257/E29.279.ccls.	EPO; JPO	OR	ON	2007/05/29 18:15
L27	32	((amorphous adj1 silicon ".alpha.si" "a-si" polysilicon polycrystalline \$6crystalline silicon)near32 (lattice plane orient\$6)) and 26	EPO; JPO	OR	ON	2007/05/29 18:15